








	<h2 style="color: red;">RT1A050ZPTR</h2>
	<p>Hersteller-Teilenummer: RT1A050ZPTR</p> <hr/> <p>Hersteller / Marke: LAPIS Semiconductor</p> <hr/> <p>Teil der Beschreibung: MOSFET P-CH 12V 5A TSST8</p> <hr/> <p>Datenblätter:  RT1A050ZPTR.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 1660 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	RT1A050ZPTR
Hersteller	LAPIS Semiconductor
Beschreibung	MOSFET P-CH 12V 5A TSST8
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	1660 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	150 °C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-SMD, Flat Lead
Supplier Device-Gehäuse	8-TSST
Verlustleistung (max)	600mW (Ta)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	12V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	5A (Ta)
Rds On (Max) @ Id, Vgs	26 mOhm @ 5A, 4.5V
VGS (th) (Max) @ Id	1V @ 1mA
Gate Charge (Qg) (Max) @ Vgs	34nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	2800pF @ 6V
Antriebsspannung (Max Rds On, Min Rds On)	1.5V, 4.5V
Vgs (Max)	±10V
Verpackung	Tape & Reel (TR)














































RT1A050ZPTR ist neu im Original, Suche RT1A050ZPTR Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie RT1A050ZPTR LAPIS Semiconductor mit Garantie und Vertrauen. Anfrage RT1A050ZPTR: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>RT1C060UN TR ROHM RT1C060UN TR ROHM</p>	 <p>RT1A050ZP TR ROHM RT1A050ZP TR ROHM</p>	 <p>RT1A3906-T112-1 MITSUMI MITSUMI SOT23</p>	 <p>RT1A060AP LAPIS Semiconductor RT1A060AP ROHM</p>
 <p>RT1A045APT CR LAPIS Semiconductor MOSFET P-CH 12V 4.5A TSST8</p>	 <p>RT1A060APTR LAPIS Semiconductor MOSFET P-CH 12V 6A TSST8</p>	 <p>RT1C060UN ROHM RT1C060UN ROHM</p>	 <p>RT1A050ZP ROHM RT1A050ZP ROHM</p>

heiße Teile

Mehr

 RT114005	 RT114005	 RT114012	 RT114012	 RT114024
 RT114024	 RT114110	 RT114110	 RT1201B7	 RT1203-30PVL
 RT1206BRE0713R3	 RT1206DRE072K15	 RT1300B6	 RT1300B6TR13	 RT1300B6TR7
 RT1306GE	 RT1402B7TR7	 RT1404B7TR7	 RT1408B7	 RT141C-T12-1
 RT1465B7TR7	 RT1467B7TR7	 RT1710GQW	 RT1A045AP	 RT1A050ZP
 RT1A060AP	 RT1C060UN	 RT1E040RP	 RT1E040RPTR	 RT1E050RPTR
 RT1E060XNTPCR	 RT1N144C-T112-1	 RT1N144M	 RT1N14BC-T12-1	 RT1N14BM-T11-1
 RT1N241C-T150-1	 RT1N241C-T50-1	 RT1N241M-T112-1	 RT1N430M	 RT1N441C-T50-1
 RT1N441M	 RT1N441U-T11-1	 RT1P140M	 RT1P140U-T111-1	 RT1P141U
 RT1P141U-T111-1	 RT1P144C-T112-1	 RT1P144C-T50	 RT1P144C-T50-1	 RT1P144U-T111-1

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